

SANYO	No.2675	DM4011
		40 characters x 1 line LIQUID CRYSTAL DOT MATRIX DISPLAY MODULE

General Description

The DM4011 is a liquid crystal dot matrix display module that consists of LCD panel LCD-5414, LCD control driver HD44780, driver LC7930 and is capable of providing 40 characters x 1 line display. It contains a controller, a data RAM, and a character generator ROM required for providing display. Data interfacing is in 8-bit parallel or 4-bit parallel and data can be written in or read from a microprocessor.

General Specifications

- | | |
|--------------------------------|--|
| 1. Display method | 1/4bias 1/11duty |
| 2. Display content | 40 characters x 1 line |
| 3. Dots organizing 1 character | 5 x 7 dots 5 x 11 dots |
| 4. Display data RAM | 80 x 8 bits |
| 5. Character generator ROM | 160-character JIS font set + 32-character special font set Refer to Table 1. |
| 6. Character generator RAM | 64 x 8 bits 5 x 7 dots 8 characters
5 x 10dots 4 characters |
| 7. Instruction function | Refer to Table 2. |
| 8. Circuit diagram | Refer to Fig. 3. |

Outline

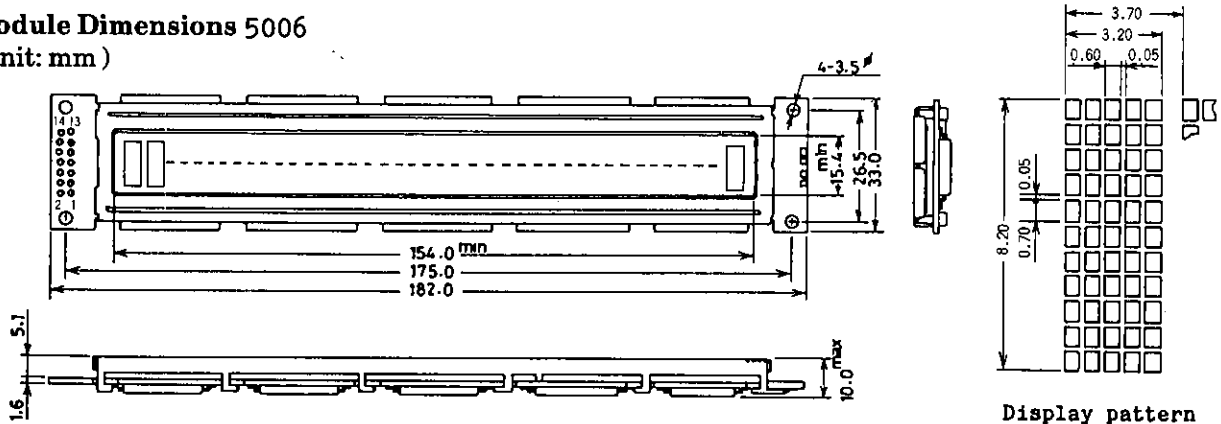
- | | |
|------------------------------|---|
| 1. Module outline | 33.0(W) x 182.0(L) x 10(T) (mm ³) |
| 2. View area | 154.0 x 15.4 (mm ²) |
| 3. Dot size | 0.60 x 0.70 (mm ²) |
| 4. Dot pitch | 0.65 x 0.75 (mm ²) |
| 5. Character size(5x11 dots) | 3.20 x 8.20 (mm ²) |

Absolute Maximum Ratings at Ta=25°C

			unit
Maximum Supply Voltage	$V_{DD}-V_{SS}$	-0.3 to +7	V
Input Voltage	V_I	-0.3 to $V_{DD}+0.3$	V
LCD Drive Voltage	$V_{DD}-V_O$	-0.3 to +9	V
Operating Temperature	T_{opr}	0 to +50	°C
Storage Temperature	T_{stg}	-20 to +70	°C

Module Dimensions 5006

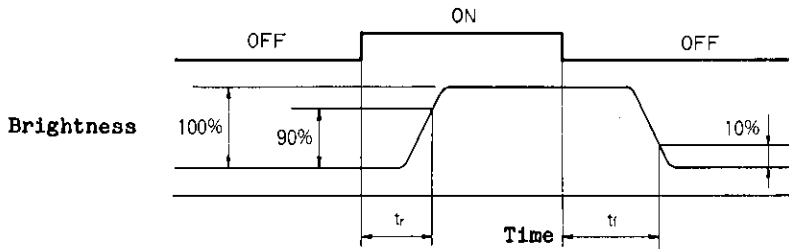
(unit: mm)



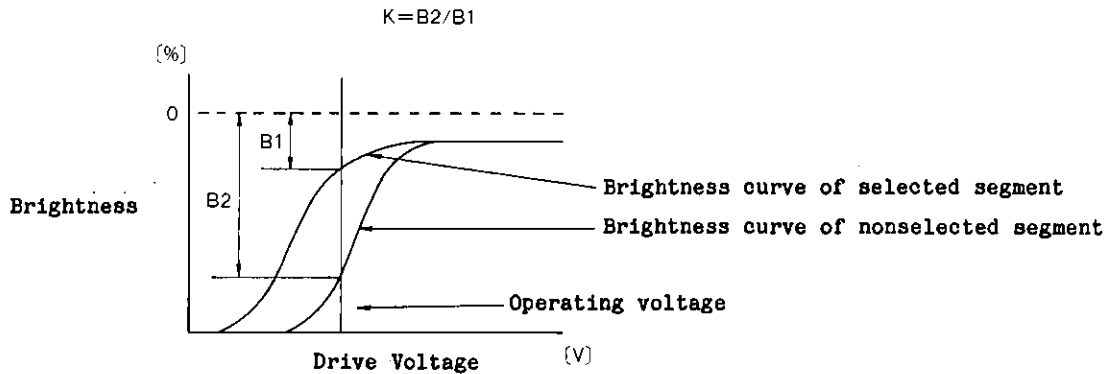
Electro-optical Characteristics at $T_a=25^{\circ}\text{C}$, $V_{DD}-V_{SS}=5\text{V}$ unless otherwise specified

		min	typ	max	unit
Input "High" Voltage	V_{IH}	2.2		5.0	V
Input "Low" Voltage	V_{IL}	0		0.6	V
Output "High" Voltage	V_{OH}	2.4			V
Output "Low" Voltage	V_{OL}			0.4	V
Pull-up MOS Current	I_P	50	125	250	μA
Current Dissipation	I_{DD}		(1.5)	3.0	mA
		No input/output current included			
Oscillation Frequency	F_{OSC}	190	270	350	kHz
Viewing Angle	$\phi 2-\phi 1$		20		degree
Contrast Ratio	K	3.0			
Rise Time	t_r		150	250	ms
Fall Time	t_f		150	250	ms
LCD Drive Voltage	$V_{DD}-V_0$				V
(Recommended Value)					V
1/11 duty					V

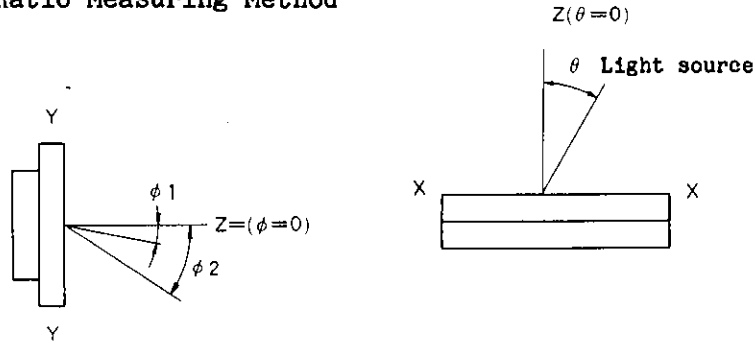
(1) Test Condition for Response Time (t_r , t_f)



(2) Definition of Contrast Ratio (K)



(3) Contrast Ratio Measuring Method



Angles ϕ and θ are defined as shown above.

The light source is placed in the θ direction at an angle of 30° and the sensor is placed in the ϕ direction to measure the contrast.

Pin Description

No.	Pin Name	Function
1	V _{SS}	(-) power supply pin 0V
2	V _{DD}	(+) power supply pin +5V
3	V _O	Pin for applying LCD drive voltage
4	RS	Input pin, HI=Data, LOW=Instruction
5	R/W	Input pin, HI=Read, LOW=Write
6	E	Input pin, Enable signal
7	DB0	Data bus line
8	DB1	
9	DB2	
10	DB3	
11	DB4	
12	DB5	
13	DB6	
14	DB7	

Timing Characteristics

			min	typ	max	unit
Enable Cycle Time		t_{cycE}	1000			ns
Enable Pulse Width	High level	PW_{EH}	450			ns
Enable Rise/Fall Time		$t_{\text{Er}}, t_{\text{Ef}}$			25	ns
Setup Time	RS, R/W, E	t_{As}	140			ns
Address Hold Time		t_{AH}	10			ns
Data Delay Time		t_{DDR}			320	ns
Data Setup Time		t_{DSW}	195			ns
Data Hold Time		$t_{\text{H}}(t_{\text{DHR}})$	10(20)			ns

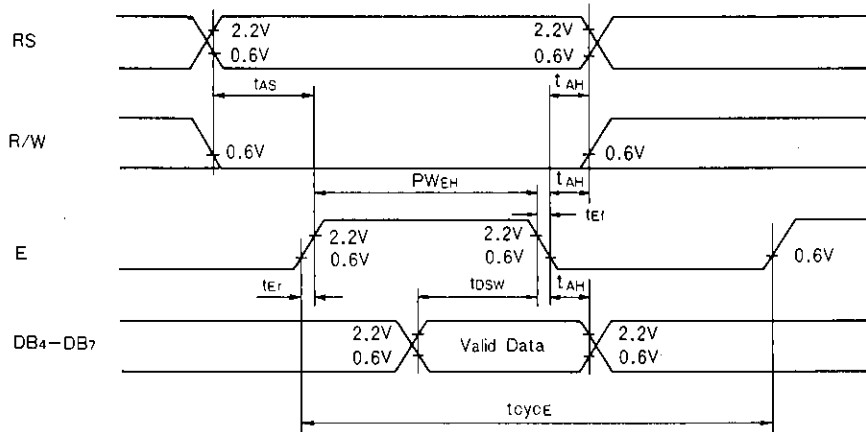
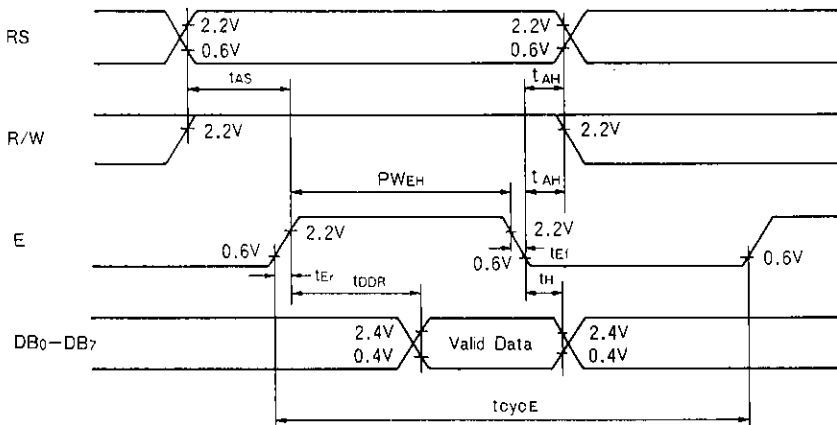
Write Operation**Fig. 1 Interface Timing (Data Write)****Read Operation****Fig. 2 Interface Timing (Data Read)**

Table 1 Character Code

Hi-order 4 bits Low-order 4 bits	0000	0010	0011	0100	0101	0110	0111	1010	1011	1100	1101	1110	1111
xxxx0000	CG RAM (1)		0	a	P	'	P	-	9	3	o	p	
xxxx0001	(2)	!	1	A	Q	a	9	a	7	9	4	a	q
xxxx0010	(3)	"	2	B	R	b	r	"	4	u	x	p	e
xxxx0011	(4)	#	3	C	S	c	s	#	5	t	e	e	e
xxxx0100	(5)	\$	4	D	T	d	t	\$	6	t	t	p	a
xxxx0101	(6)	%	5	E	U	e	u	%	7	u	u	e	o
xxxx0110	(7)	&	6	F	V	f	v	&	8	v	c	p	z
xxxx0111	(8)	'	7	G	W	g	w	'	9	w	z	q	x
xxxx1000	(1)	(8	H	X	h	x	(0	x	v	r	x
xxxx1001	(2))	9	I	Y	i	y)	1	y	u	'	y
xxxx1010	(3)	*	#	J	Z	j	z	*	2	z	v	j	f
xxxx1011	(4)	+	\$	K	[k	[+	3	[e	*	k
xxxx1100	(5)	,	<	L	\	l	\	,	4	\	o	o	k
xxxx1101	(6)	-	=	M]	m]	-	5]	o	k	+
xxxx1110	(7)	.	>	N	^	n	^	.	6	^	o	k	
xxxx1111	(8)	/	?	O	_	o	_	/	7	_	o	o	

(Note) The CG RAM is a character generator RAM used to store the character patterns that can be program-rewritten, as desired, by the user.

Table 2 Instruction Function

Instruction	Code										Contents	Execution Time ($f_{OSC}=250kHz$)
	RS	R/W	DB7	DB6	DB5	DB4	DB3	DB2	DB1	DB0		
Display clear	0	0	0	0	0	0	0	0	0	1	Clears all display and returns the cursor to the home position (address 0).	82 μ s to 1.64ms
Cursor home	0	0	0	0	0	0	0	0	1	*	Returns the cursor to the home position (address 0). Also returns the display being shifted to the original position. The DD RAM contents remain unaffected.	40 μ s to 1.6ms
Entry mode set	0	0	0	0	0	0	0	1	I/D	S	Sets the cursor move direction and specifies whether or not to shift the display. These operations are performed during data write and read.	40 μ s
Display ON/OFF control	0	0	0	0	0	0	1	D	C	B	Sets all display ON/OFF(D), cursor ON/OFF(C), cursor position character blink (B).	40 μ s
Cursor/display shift	0	0	0	0	0	1	S/C	R/L	*	*	Moves the cursor and shifts the display without affecting the DD RAM contents.	40 μ s
Function set	0	0	0	0	1	DL	N	F	*	*	Sets the interface data length (DL), number of display lines (L), and character font (F).	40 μ s
CG RAM address set	0	0	0	1	A _{CG}					Sets the CG RAM address. RAM data is sent/received after this setting.		40 μ s
DD RAM address set	0	0	1	A _{DD}					Sets the DD RAM address. DD RAM data is sent/received after this setting.		40 μ s	
Busy flag/address read	0	1	BF	AC					Reads the contents of busy flag (BF) indicating internal operation is in progress and reads the contents of address counter.		1 μ s	
CG RAM/DD RAM data write	1	0	Write Data					Writes data into the DD RAM or CG RAM.		40 μ s		
CG RAM/DD RAM data read	1	1	Read Data					Reads data from the DD RAM or CG RAM.		40 μ s		
	I/D=1: Increment (+1) I/D=0: Decrement (-1) S=1: Accompanied by display shift S/C=1: Display shift S/C=0: Cursor move R/L=1: Right-shift R/L=0: Left-shift DL=1: 8 bits DL=0: 4 bits N=1: 2 lines N=0: 1 line F=1: 5 x 10 dots F=0: 5 x 7 dots BF=1: Internally operating BF=0: Possible to accept instruction										DD RAM: Display data RAM CG RAM: Character generator RAM A _{CG} : CG RAM address A _{DD} : DD RAM address Corresponds to cursor address. AC: Address counter used for both DD RAM and CG RAM.	The change in the frequency (f_{OSC}) also causes the execution time to be changed. (Example) When $f_{OSC}=270kHz,$ $40\mu s \times \frac{250}{270} =$ $37\mu s.$

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Fig. 3 Circuit Diagram DM4011

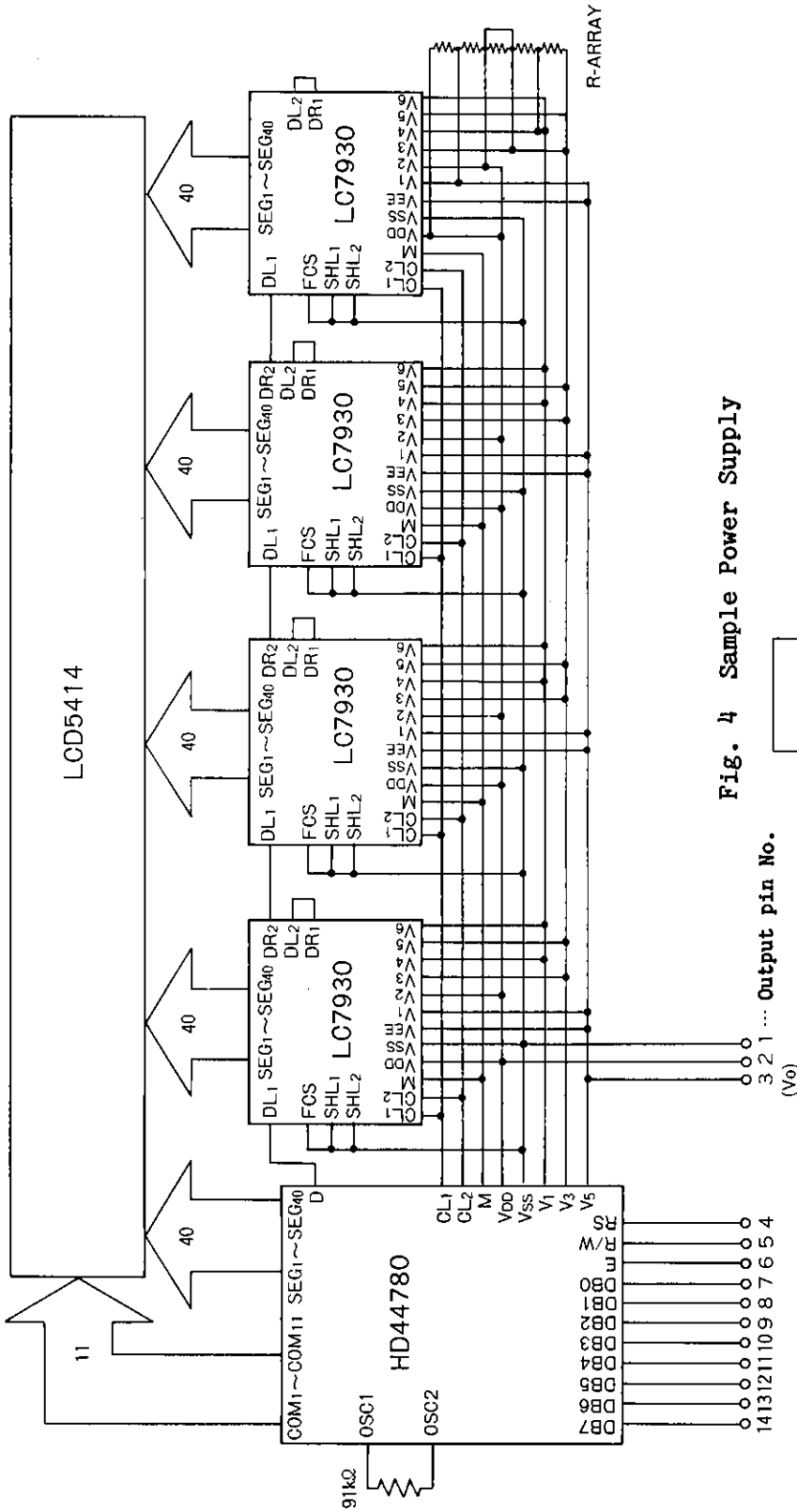
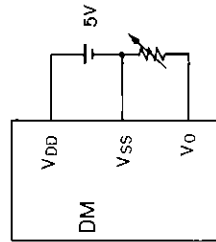


Fig. 4 Sample Power Supply



3.2 1 ... Output pin No. (Vo)

V_{DD}-V₀: LCD drive voltage
 The LCD drive voltage can be varied from approximately 3V to 5V by a variable resistor of 5kohms connected across V_{SS} and V₀.